



ON Semiconductor®

Diode Forward Voltage Spread

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Background

- **Maintain Power Signature Balance**
- **Pairset Power Balance**

Tested Devices

- **MBR1H100SF** **100V, 1A Schottky**
- **MBRS2H100** **100V, 2A Schottky**
- **MBRS1100** **100V, 2A Schottky**
- **SBRS81100** **100V, 2A Schottky, Auto**

Test Methodology (Low Power)

V_f test inserted in production testing

- **5 mA (212.5/285 mW @ 42.5/57V)**
- **10 mA (425/570 mW @ 42.5/57V)**
- **20 mA (850/1140 mW @ 42.5/57V)**

Devices (Low Power)

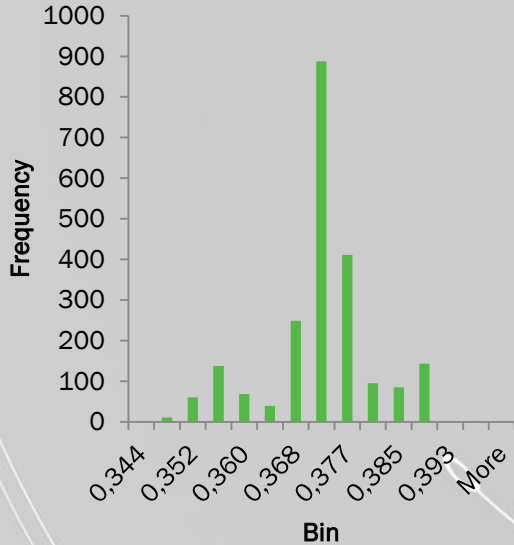
- **MBR1H100SF** **2188**
- **MBRS2H100** **410**
- **MBRS1100** **65021**
- **SBRS81100** **4038**

Low Power Summary

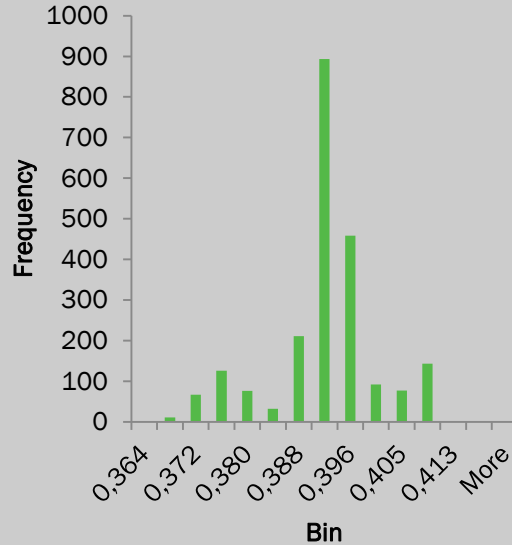
| | | Part Number | | | | |
|-----------|------|-------------|----------------|----------|-----------|-------|
| | | MBR1H100SF | MBRS2H100 | MBRS1100 | SBRS81100 | |
| VF @ IF = | 5mA | Ave | 0,371 | 0,318 | 0,335 | 0,339 |
| | | Std Dev | 0,008 | 0,003 | 0,004 | 0,011 |
| | | Min | 0,344 | 0,310 | 0,205 | 0,252 |
| | | Max | 0,389 | 0,330 | 0,346 | 0,354 |
| | 10mA | Ave | 0,390 | 0,337 | 0,355 | 0,359 |
| | | Std Dev | 0,008 | 0,003 | 0,004 | 0,011 |
| | | Min | 0,364 | 0,328 | 0,224 | 0,270 |
| | | Max | 0,412 | 0,349 | 0,366 | 0,372 |
| | 20mA | Ave | 0,412 | 0,356 | 0,376 | 0,380 |
| | | Std Dev | 0,008 | 0,003 | 0,004 | 0,011 |
| | | Min | 0,387 | 0,348 | 0,242 | 0,290 |
| | | Max | 0,455 | 0,368 | 0,388 | 0,394 |
| | | | Max ΔV | 0.068 | 0.020 | 0.146 |
| | | # Devices | 2188 | 410 | 65021 | 4038 |

MBR1H100SFT3G

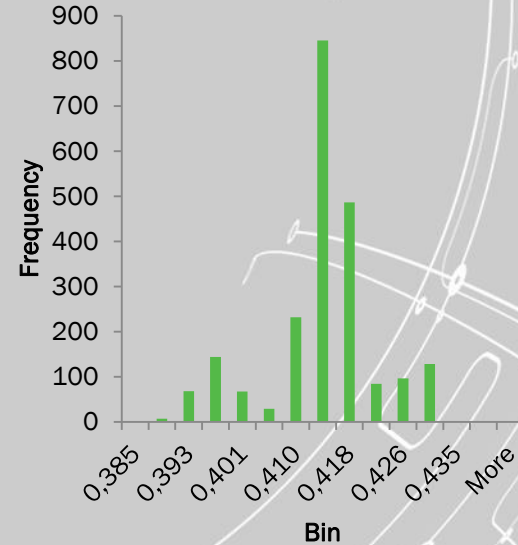
5 mA



10 mA

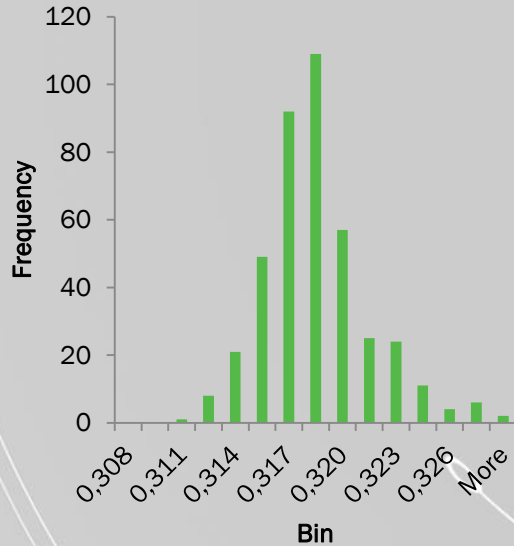


20 mA

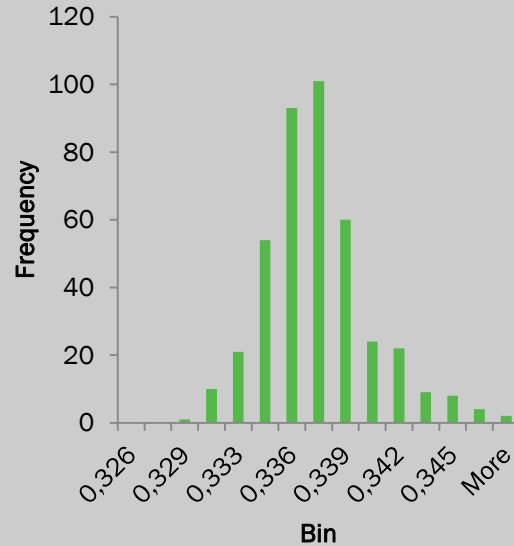


MBRS2H100T3G

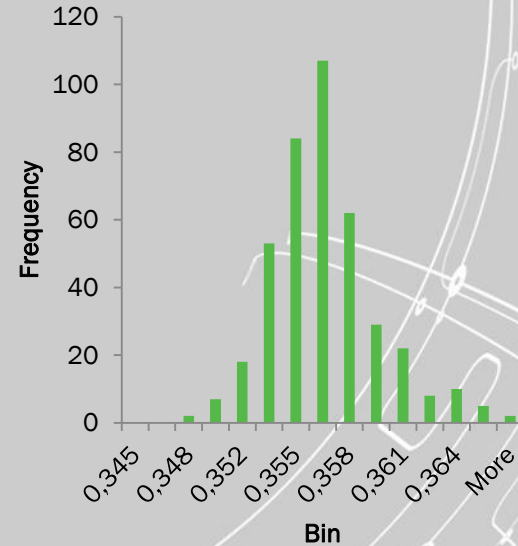
5 mA



10 mA

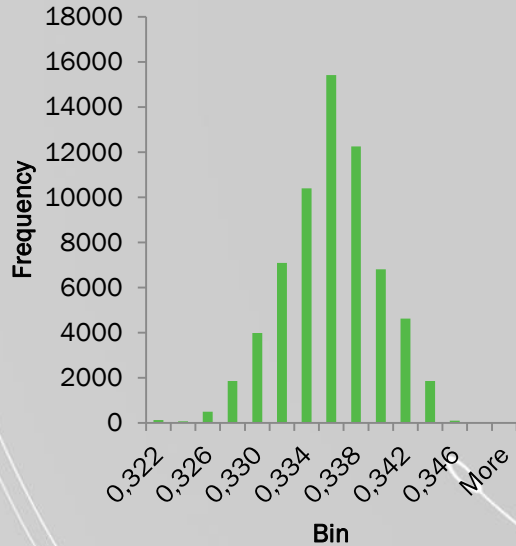


20 mA

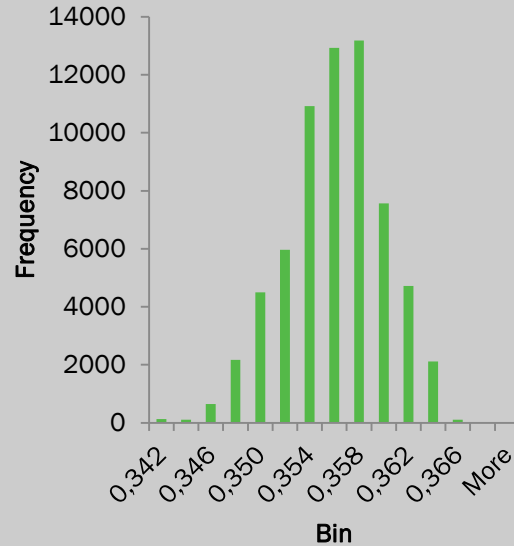


MBRS1100T3G

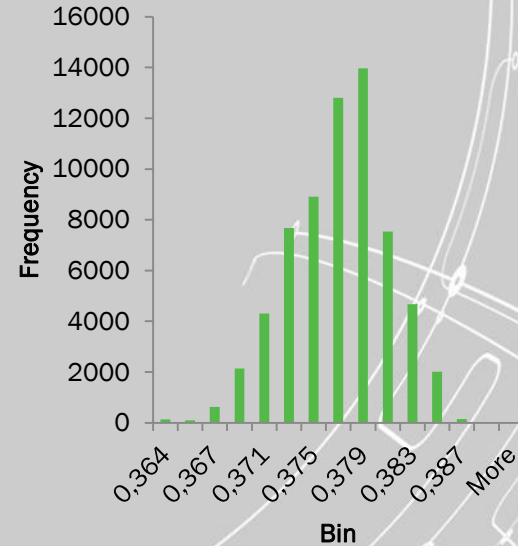
5 mA



10 mA

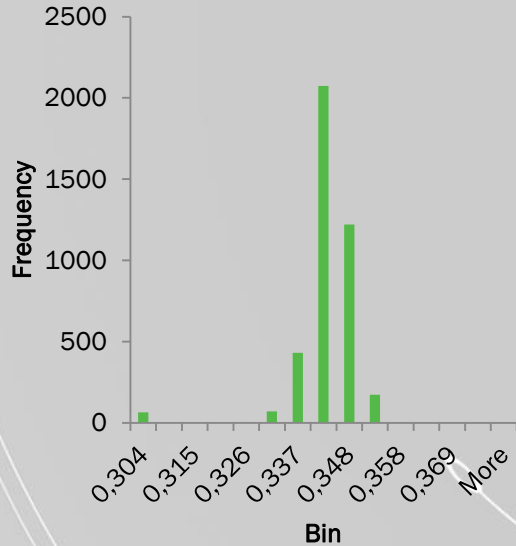


20 mA

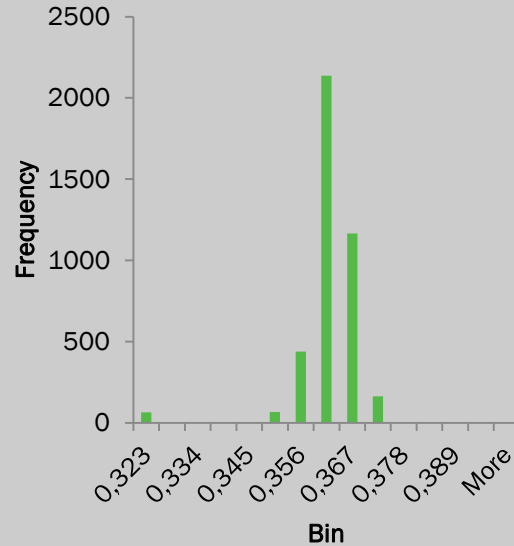


SBRS81100T3G

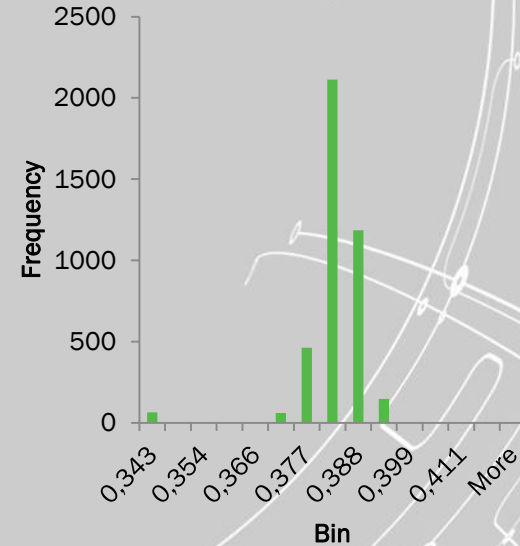
5 mA



10 mA



20 mA



Influence on Pairset Balance

$$\Delta I/I = 2\Delta V/I/R_{\text{pairset}}$$

R_{pairset} includes cable, magnetics, etc..

Example: 10mA, worst case, $R_{\text{pairset}} = 1\Omega$

$$\Delta I/I = 2 * 142 \text{ mV} / 10\text{mA} / 1 = 28.4$$

Test Methodology (High Power)

Vf test in production testing

- **1A** (**42.5/57W @ 42.5/57V**)
- **2A** (**85W/114W @ 42.5/57V**)

Devices (High Power)

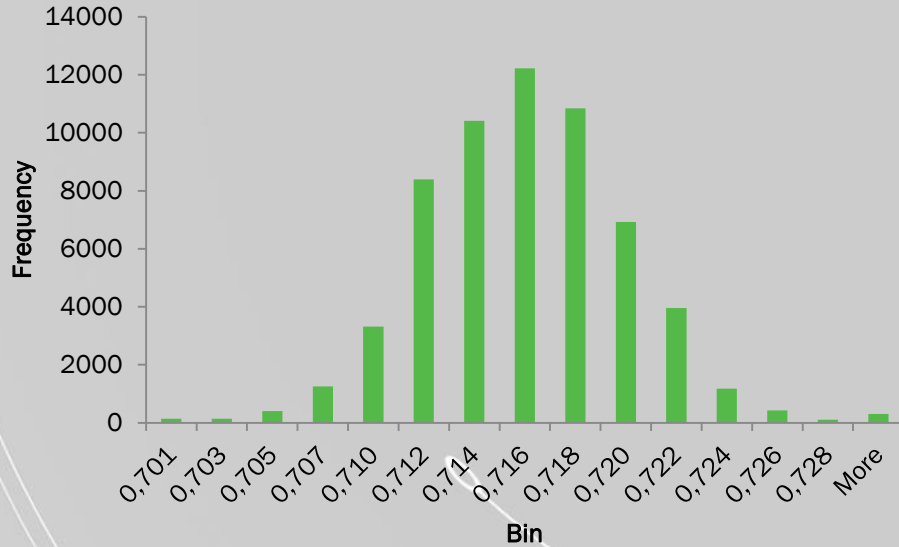
- **MBR1H100SF** **60014**
- **MBRS2H100** **6355**
- **MBRS1100** **32480**
- **SBRS81100** **53169**

High Power Summary

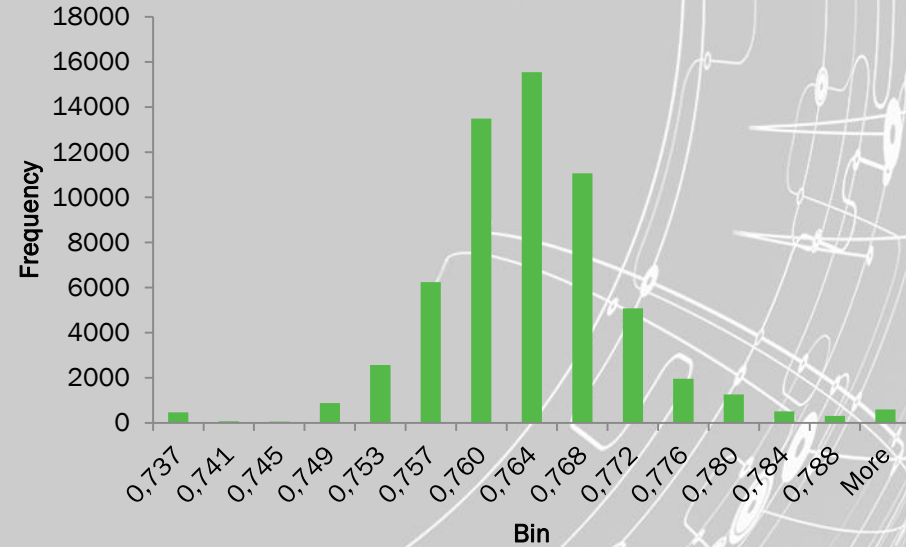
| | | Part Number | | | | | |
|-----------|-----|-------------|-----------|----------|-----------|---------|--------|
| | | MBR1H100SF | MBRS2H100 | MBRS1100 | SBRS81100 | | |
| VF @ IF = | 1 A | Ave | 0,715 | 0,557 | 0,675 | 0,684 | |
| | | Std Dev | 0,00417 | 0,00737 | 0,00381 | 0,00495 | |
| | | Min | 0,6784 | 0,5224 | 0,6448 | 0,6472 | |
| | | Max | 0,7388 | 0,5772 | 0,7116 | 0,7128 | |
| | 2 A | Ave | 0,762 | 0,650 | | | |
| | | Std Dev | 0,00791 | 0,00734 | | | |
| | | Min | 0,7016 | 0,6212 | | | |
| | | Max | 0,8096 | 0,6716 | | | |
| | | | Max ΔV | 0.108 | 0.0548 | 0.0668 | 0.0656 |
| | | | # Devices | 60014 | 6355 | 32480 | 53169 |

MBR1H100SFT3G

1 A

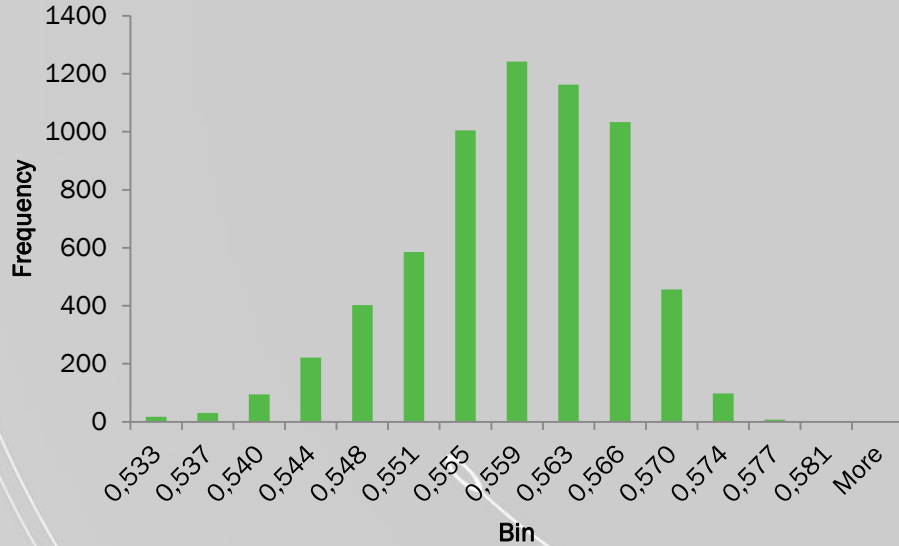


2 A

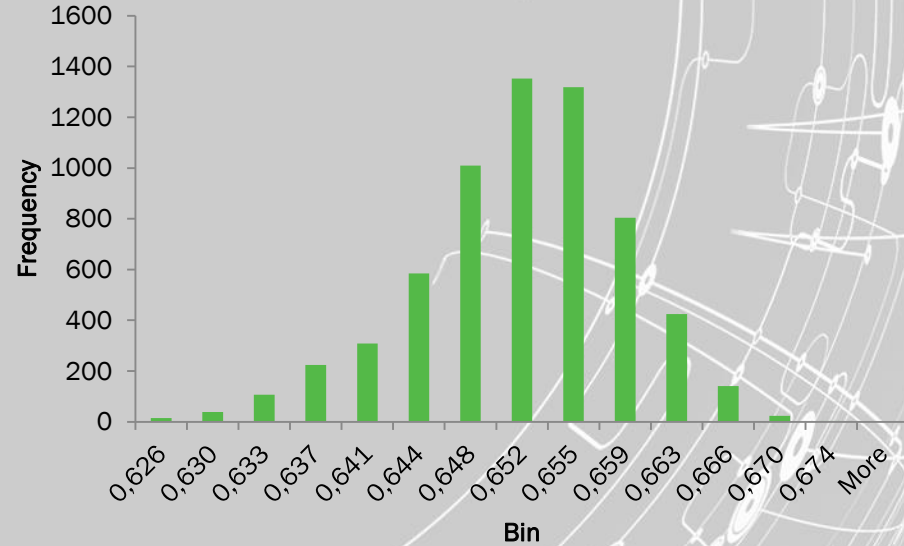


MBRS2H100T3G

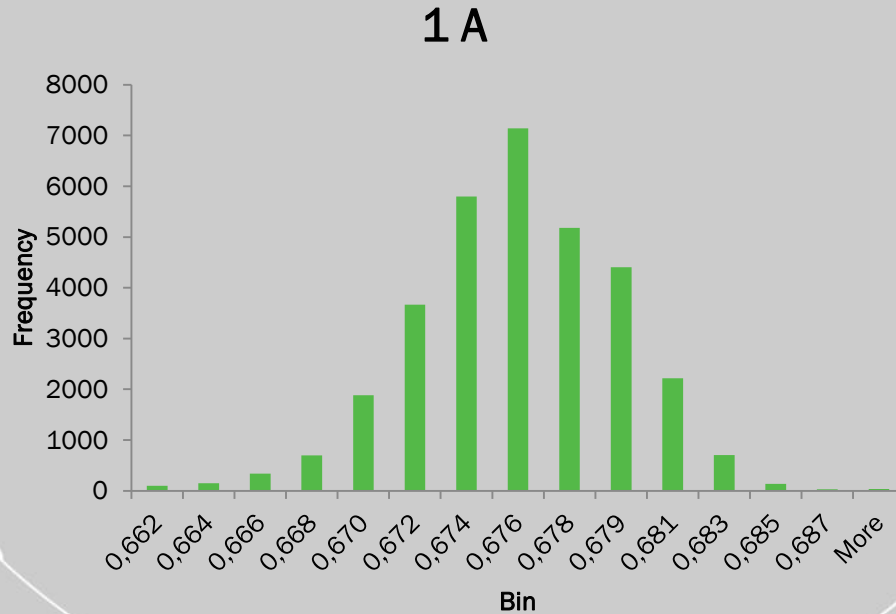
1 A



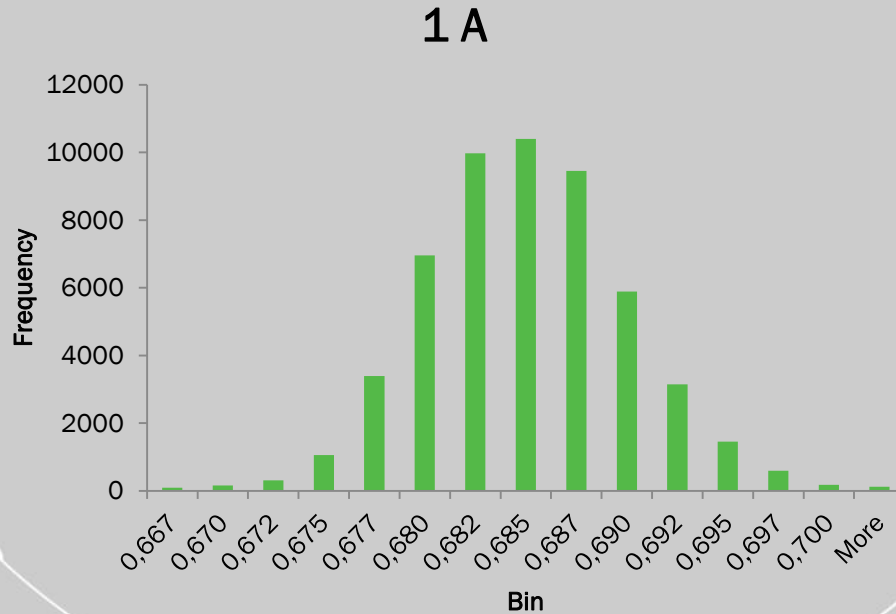
Histogram



MBRS1100T3G



SBRS81100T3G



Influence on Pairset Balance

$$\Delta I/I = 2\Delta V/I/R_{\text{pairset}}$$

R_pairset includes cable, magnetics, etc..

Example: 1A, worst case, R_pairset = 1Ω

$$\Delta I/I = 2 * 108 \text{ mV} / 1 \text{ A} / 1 = 0.216$$

Conclusion

- **Standard deviation is small**
- **Forward voltage spread is large**
 - enough to cause unbalance of MPS currents
 - not enough to cause unbalance of high currents
- **Can be worse when diodes happen to be from different lots/fabs**

Further Study

- **Forward Voltage Spread for higher current rating diodes**